MMVL105GT1

Preferred Device

Silicon Tuning Diode

This device is designed in the Surface Mount package for general frequency control and tuning applications. It provides solid–state reliability in replacement of mechanical tuning methods.

- Controlled and Uniform Tuning Ratio
- Device Marking: 4E



ON Semiconductor™

http://onsemi.com

30 VOLT VOLTAGE VARIABLE CAPACITANCE DIODE

MAXIMUM RATINGS

| Symbol | Rating | Value | Unit |
|--------|----------------------------|-------|------|
| ٧R | Continuous Reverse Voltage | 30 | Vdc |
| lF | Peak Forward Current | 200 | mAdc |

THERMAL CHARACTERISTICS

| Symbol | Characteristic | Max | Unit |
|-----------------------------------|---|-------------|-------------|
| P _D | Total Device Dissipation FR–5 Board,* TA = 25°C Derate above 25°C | 200 1.57 | mW mW/°C |
| $R_{\theta JA}$ | Thermal Resistance Junction to Ambient | 635 | °C/W |
| T _J , T _{stg} | Junction and Storage Temperature | 150 | °C |

^{*}FR-4 Minimum Pad



PLASTIC SOD-323 CASE 477



ORDERING INFORMATION

| Device | | Package | Shipping | | |
|--------|------------|---------|--------------------|--|--|
| | MMVL105GT1 | SOD-323 | 3000 / Tape & Reel | | |

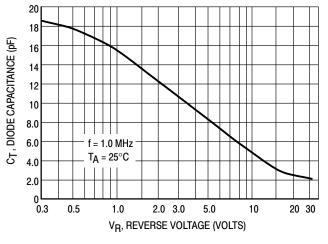
Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|---|--------|--------|-----|-----|------|
| Reverse Breakdown Voltage (I _R = 10 μAdc) | | V(BR)R | 30 | _ | Vdc |
| Reverse Voltage Leakage Current (V _R = 28 Vdc) | | IR | _ | 50 | nAdc |

| Device Type | C _T V _R = 25 Vdc, f = 1.0 MHz pF | | Q V _R = 3.0 Vdc f = 50 MHz | C _R C ₃ /C ₂₅ f = 1.0 MHz | |
|-------------|--|-----|---|--|-----|
| | Min | Max | Тур | Min | Max |
| MMVL105GT1 | 1.5 | 2.8 | 250 | 4.0 | 6.5 |

TYPICAL CHARACTERISTICS



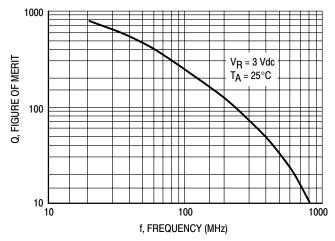


Figure 1. Diode Capacitance

Figure 2. Figure of Merit

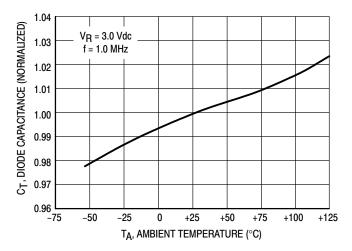
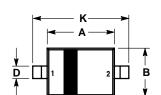


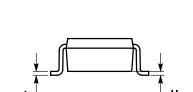
Figure 3. Diode Capacitance

MMVL105GT1

PACKAGE DIMENSIONS



SOD-323 PLASTIC PACKAGE CASE 477-02 **ISSUE A**



NOTE 3



- NOTES:

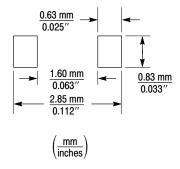
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.

| | MILLIN | IETERS | INCHES | | |
|-----|----------|--------|-----------|--------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 1.60 | 1.80 | 0.063 | 0.071 | |
| В | 1.15 | 1.35 | 0.045 | 0.053 | |
| С | 0.80 | 1.00 | 0.031 | 0.039 | |
| D | 0.25 | 0.40 | 0.010 | 0.016 | |
| Е | 0.15 REF | | 0.006 REF | | |
| Н | 0.00 | 0.10 | 0.000 | 0.004 | |
| J | 0.089 | 0.177 | 0.0035 | 0.0070 | |
| K | 2.30 | 2.70 | 0.091 | 0.106 | |

STYLE 1: PIN 1. CATHODE 2. ANODE



SOD-323 Soldering Footprint

MMVL105GT1

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